

# LM78L00 Series 3-Terminal Positive Voltage Regulators

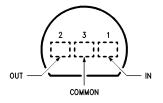
#### **General Description**

The LM78L00 series of 3-terminal positive voltage regulators employ internal current-limiting and thermal shutdown, making them essentially indestructible. If adequate heat sinking is provided, they can deliver up to 100 mA output current. They are intended as fixed voltage regulators in a wide range of applications including local (on-card) regulation for elimination of noise and distribution problems associated with single-point regulation. In addition, they can be used with power pass elements to make high current voltage regulators. The LM78L00, used as a Zener diode/resistor combination replacement, offers an effective output impedance improvement of typically two orders of magnitude, along with lower quiescent current and lower noise.

#### **Features**

- Output current up to 100 mA
- No external components
- Internal thermal overload protection
- Internal short circuit current-limiting
- Available in JEDEC TO-92
- Output Voltages of 5.0V, 6.2V, 8.2V, 9.0V, 12V, 15V
- $\blacksquare$  Output voltage tolerances of  $\pm 5\%$  over the temperature range

#### **Connection Diagram**



TL/H/10051-1

**Top View** 

Order Number LM78L05ACZ, LM78L09ACZ, LM78L12ACZ, LM78L15ACZ, LM78L62ACZ or LM78L82ACZ See NS Package Number Z03A

#### **Absolute Maximum Ratings**

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Storage Temperature Range

-65°C to +150°C

Operation Junction Temperature Range

Commercial (LM78L00AC)

0°C to +125°C

Lead Temperature TO-92 Package/SO-8 (Soldering, 10 sec.)

Power Dissipation Input Voltage 5.0V to 15V

Internally Limited

265°C

35V

ESD Susceptibility

to be determined

#### LM78L05AC

#### **Electrical Characteristics**

0°C  $\leq$  T<sub>A</sub>  $\leq$  + 125°C, V<sub>I</sub> = 10V, I<sub>O</sub> = 40 mA, C<sub>I</sub> = 0.33  $\mu\text{F},$  C<sub>O</sub> = 0.1  $\mu\text{F},$  unless otherwise specified (Note 1)

Symbol	Parameter		Conditions		Min	Тур	Max	Units
Vo	Output Voltage		$T_{J} = 25^{\circ}C$		4.8	5.0	5.2	V
V <sub>R LINE</sub>	Line Regulation		$T_J = 25^{\circ}C$	$7.0V \le V_I \le 20V$		55	150	mV
				$8.0V \le V_l \le 20V$		45	100	1110
V <sub>R LOAD</sub>	Load Regulation		$T_{J} = 25^{\circ}C$	$1.0 \text{ mA} \leq I_{O} \leq 100 \text{V}$		11	60	mV
				$1.0 \text{ mA} \leq I_{O} \leq 40 \text{ mA}$		5.0	30	1110
Vo	Output Voltage (Note 2)		$7.0V \leq V_{I} \leq 20V$	$1.0 \text{ mA} \leq I_{O} \leq 40 \text{ mA}$	4.75		5.25	V
			$7.0V \le V_I \le V_{Max}$	$1.0 \text{ mA} \leq I_{O} \leq 70 \text{ mA}$	4.75		5.25	, v
IQ	Quiescent Current					2.0	5.5	mA
$\Delta I_Q$	Q Quiescent Current		$8.0V \le V_I \le 20V$				1.5	mA
	Change	With Load	$1.0 \text{ mA} \leq I_{O} \leq 40 \text{ mA}$				0.1	] ""(
N <sub>O</sub>	Noise		T <sub>A</sub> = 25°C, 10 Hz ≤	≤ f ≤ 100 kHz		40		μV
$\Delta V_I / \Delta V_O$	Ripple Rejection		$f = 120 \text{ Hz}, 8.0 \text{V} \le \text{V}_{\text{I}} \le 18 \text{V}, \text{T}_{\text{J}} = 25 ^{\circ} \text{C}$		41	49		dB
$V_{DO}$	Dropout Voltage		$T_J = 25^{\circ}C$			1.7		V
I <sub>pk</sub> /I <sub>OS</sub>	Peak Output/Output Short Circuit Current		$T_{J} = 25^{\circ}C$			140		mA
ΔV <sub>O</sub> /ΔΤ	Average Temperatu Coefficient of Outpu		I <sub>O</sub> = 5.0 mA			-0.65		mV/°C

Note 1: The maximum steady state usable output current and input voltage are very dependent on the heat sinking and/or lead length of the package. The data above represent pulse test conditions with junction temperatures as indicated at the initiation of tests.

Note 2: Power Dissipation  $\leq$  0.75W.

#### LM78L62AC

**Electrical Characteristics** 0°C  $\leq$  T<sub>A</sub>  $\leq$  + 125°C, V<sub>I</sub> = 12V, I<sub>O</sub> = 40 mA, C<sub>I</sub> = 0.33  $\mu$ F, C<sub>O</sub> = 0.1  $\mu$ F, unless otherwise specified (Note 1)

Symbol	Parameter		Conditions		Min	Тур	Max	Units
Vo	Output Voltage		$T_{J} = 25^{\circ}C$		5.95	6.2	6.45	V
V <sub>R LINE</sub>	Line Regulation		$T_{J} = 25^{\circ}C$	$8.5V \le V_I \le 20V$		65	175	mV
	 			$9.0V \leq V_{I} \leq 20V$		55	125	
V <sub>R LOAD</sub>	Load Regulation		$T_{J} = 25^{\circ}C$	$1.0~\text{mA} \leq I_{O} \leq 100~\text{mA}$		13	80	mV
				$1.0~\text{mA} \leq I_{O} \leq 40~\text{mA}$		6.0	40	
Vo	Output Voltage (Note 2)		$8.5V \le V_I \le 20V$	$1.0~\text{mA} \leq I_{\text{O}} \leq 40~\text{mA}$	5.90		6.5	V
			$8.5V \leq V_I \leq V_{Max}$	$1.0~\text{mA} \leq I_{O} \leq 70~\text{mA}$	5.90		6.5	•
IQ	Quiescent Current					2.0	5.5	mA
ΔlQ	Quiescent Current With Line Change With Load		$8.0V \leq V_{I} \leq 20V$				1.5	mA
			$1.0 \text{ mA} \leq I_{O} \leq 40 \text{ mA}$				0.1	
N <sub>O</sub>	Noise	Noise T <sub>A</sub> = 25°		$\leq f \leq 100 \text{ kHz}$		50		μV
$\Delta V_I / \Delta V_O$	Ripple Rejection		f = 120 Hz, 10V ≤	$V_{I} \le 20V$ , $T_{J} = 25^{\circ}C$	40	46		dB
$V_{DO}$	Dropout Voltage		$T_{J} = 25^{\circ}C$			1.7		V
I <sub>pk</sub> /I <sub>OS</sub>	Peak Output/Output Short Circuit Current		$T_{J} = 25^{\circ}C$			140		mA
ΔV <sub>O</sub> /ΔΤ	Average Temperatu Coefficient of Outpu		I <sub>O</sub> = 5.0 mA			-0.75		mV/°C

#### LM78L82AC

#### **Electrical Characteristics**

 $0^{\circ}\text{C} \leq \text{T}_{A} \leq +125^{\circ}\text{C}, \ \text{V}_{I} = 14 \text{V}, \ \text{I}_{O} = 40 \ \text{mA}, \ \text{C}_{I} = 0.33 \ \mu\text{F}, \ \text{C}_{O} = 0.1 \ \mu\text{F}, \ \text{unless otherwise specified (Note 1)}$ 

Symbol	Parameter		Conditions		Min	Тур	Max	Units
Vo	Output Voltage		$T_{J} = 25^{\circ}C$		7.87	8.2	8.53	V
V <sub>R LINE</sub>	Line Regulation		$T_J = 25^{\circ}C$	$11V \leq V_I \leq 23V$		80	175	mV
				$12V \leq V_{I} \leq 23V$		70	125	
V <sub>R LOAD</sub>	Load Regulation		$T_J = 25^{\circ}C$	$1.0~\text{mA} \leq I_{O} \leq 100~\text{mA}$		15	80	mA
				$1.0~\text{mA} \leq I_{O} \leq 40~\text{mA}$		8.0	40	111/
V <sub>O</sub>	Output Voltage (Note 2)		$11V \leq V_I \leq 23V$	$1.0 \text{ mA} \leq I_{O} \leq 40 \text{ mA}$	7.8		8.5	V
			$11V \leq V_I \leq V_{Max}$	$1.0~\text{mA} \leq I_{O} \leq 70~\text{mA}$	7.8		8.6	•
IQ	Quiescent Current	Quiescent Current			2.1	5.5	mA	
$\Delta I_{Q}$	Quiescent Current	With Line	$12V \leq V_I \leq 23V$	$V_{I} \leq 23V$			1.5	mA
	Change	With Load	$1.0~\text{mA} \leq I_{ extsf{O}} \leq 40~\text{m}$	mA			0.1	1117 (
N <sub>O</sub>	Noise		T <sub>A</sub> = 25°C, 10 Hz	$T_A=25^{\circ}C$ , 10 Hz $\leq f \leq$ 100 kHz		60		μV
$\Delta V_I / \Delta V_O$	Ripple Rejection		f = 120 Hz, 12V ≤	$V_I \leq 22V, T_J = 25^{\circ}C$	39	45		dB
V <sub>DO</sub>	Dropout Voltage		$T_J = 25^{\circ}C$			1.7		V
I <sub>pk</sub> /I <sub>OS</sub>	Peak Output/Output Short Circuit Current		$T_{J} = 25^{\circ}C$			140		mA
ΔV <sub>O</sub> /ΔΤ	Average Temperatu Coefficient of Outpu		$I_O = 5.0 \text{ mA}$			-0.8		mV/°C

Note 1: The maximum steady state usable output current and input voltage are very dependent on the heat sinking and/or lead length of the package. The data above represent pulse test conditions with junction temperatures as indicated at the initiation of tests.

Note 2: Power Dissipation  $\leq$  0.75W.

#### LM78L09AC

#### **Electrical Characteristics**

 $0^{\circ}$ C  $\leq$  T<sub>A</sub>  $\leq$  +125°C, V<sub>I</sub> = 15V, I<sub>O</sub> = 40 mA, C<sub>I</sub> = 0.33  $\mu$ F, C<sub>O</sub> = 0.1  $\mu$ F, unless otherwise specified (Note 1)

Symbol	Parameter		Conditions		Min	Тур	Max	Units
Vo	Output Voltage		T <sub>J</sub> = 25°C		8.64	9.0	9.36	V
V <sub>R LINE</sub>	Line Regulation		$T_J = 25^{\circ}C$	$11.5V \leq V_{\text{I}} \leq 24V$		90	200	mV
				$13V \leq V_{I} \leq 24V$		100	150	1111
V <sub>R LOAD</sub>	OAD Load Regulation		$T_J = 25^{\circ}C$	$1.0 \text{ mA} \leq I_{O} \leq 100 \text{ mA}$		20	90	mV
				$1.0 \text{ mA} \leq I_{O} \leq 40 \text{ mA}$		10	45	1111
Vo	Output Voltage (Note 2)		$11.5 \text{V} \leq \text{V}_{\text{I}} \leq 24 \text{V}$	$1.0 \text{ mA} \leq I_{O} \leq 40 \text{ mA}$	8.55		9.45	V
			$11.5V \le V_I \le V_{Max}$	$1.0~\text{mA} \leq I_{O} \leq 70~\text{mA}$	8.55		9.45	
IQ	Quiescent Current					2.1	5.5	mA
ΔlQ	Quiescent Current	With Line	$11.5 \text{V} \leq \text{V}_{\text{I}} \leq 24 \text{V}$				1.5	mA
	Change		$1.0 \text{ mA} \leq I_{O} \leq 40 \text{ mA}$				0.1	
N <sub>O</sub>	Noise		$T_A = 25^{\circ}C$ , 10 Hz $\leq f \leq 100 \text{ kHz}$			70		μV
$\Delta V_I/\Delta V_O$	Ripple Rejection		$f=120~Hz,15V\leq V_{\textrm{I}}\leq25V,T_{\textrm{J}}=25^{\circ}\textrm{C}$		38	44		dB
V <sub>DO</sub>	Dropout Voltage		T <sub>J</sub> = 25°C			1.7		V
I <sub>pk</sub> /I <sub>OS</sub>	Peak Output/Output Short Circuit Current		T <sub>J</sub> = 25°C			140		mA
ΔV <sub>O</sub> /ΔΤ	Average Temperatu Coefficient of Outpu		$I_{O} = 5.0 \text{ mA}$			-0.9		mV/°C

### LM78L12AC

#### **Electrical Characteristics**

 $0^{\circ}C \leq$  T<sub>A</sub>  $\leq$   $+125^{\circ}$ C, V<sub>I</sub> = 19V, I<sub>O</sub> = 40 mA, C<sub>I</sub> = 0.33  $\mu\text{F},$  C<sub>O</sub> = 0.1  $\mu\text{F},$  unless otherwise specified (Note 1)

Symbol	Parameter		Conditions		Min	Тур	Max	Units	
Vo	Output Voltage		$T_{J} = 25^{\circ}C$		11.5	12	12.5	٧	
V <sub>R LINE</sub>	Line Regulation		$T_{J} = 25^{\circ}C$	$14.5V \leq V_{I} \leq 27V$		120	250	mV	
				$16V \leq V_I \leq 27V$		100	200	1114	
V <sub>R LOAD</sub>	R LOAD Load Regulation		$T_J = 25^{\circ}C$	$1.0 \text{ mA} \leq I_{O} \leq 100 \text{ mA}$		20	100	mV	
				$1.0~\text{mA} \leq I_{O} \leq 40~\text{mA}$		10	50	1114	
Vo	Output Voltage (Note 2)		$14.5 \text{V} \leq \text{V}_{\text{I}} \leq 27 \text{V}$	$1.0 \text{ mA} \leq I_{O} \leq 40 \text{ mA}$	11.4		12.6		
			$14.5V \le V_I \le V_{Max}$	$1.0 \text{ mA} \leq I_{O} \leq 70 \text{ mA}$	11.4		12.6	•	
IQ	Quiescent Current					2.1	5.5	mA	
ΔlQ	Quiescent Current Change		$16V \le V_I \le 27V$				1.5	mA	
			$1.0 \text{ mA} \leq I_{O} \leq 40 \text{ mA}$				0.1	IIIA	
N <sub>O</sub>	Noise		$T_A=25^{\circ}C$ , 10 Hz $\leq f \leq$ 100 kHz			80		μV	
$\Delta V_I / \Delta V_O$	Ripple Rejection		$f = 120 \text{ Hz}, 15 \text{V} \le \text{V}_{\text{I}} \le 25 \text{V}, \text{T}_{\text{J}} = 25 ^{\circ}\text{C}$		37	42		dB	
V <sub>DO</sub>	Dropout Voltage		$T_{J} = 25^{\circ}C$			1.7		V	
I <sub>pk</sub> /I <sub>OS</sub>	Peak Output/Output Short Circuit Current		$T_{J} = 25^{\circ}C$			140		mA	
ΔV <sub>O</sub> /ΔΤ	Average Temperatu Coefficient of Output		I <sub>O</sub> = 5.0 mA			-1.0		mV/°C	

Note 1: The maximum steady state usable output current and input voltage are very dependent on the heat sinking and/or lead length of the package. The data above represent pulse test conditions with junction temperatures as indicated at the initiation of tests.

Note 2: Power Dissipation  $\leq 0.75W$ .

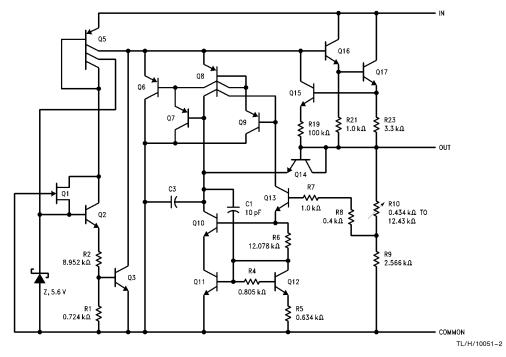
# LM78L15AC

**Electrical Characteristics** 0°C  $\leq$  T<sub>A</sub>  $\leq$  + 125°C, V<sub>I</sub> = 23V, I<sub>O</sub> = 40 mA, C<sub>I</sub> = 0.33  $\mu\text{F},$  C<sub>O</sub> = 0.1  $\mu\text{F},$  unless otherwise specified (Note 1)

Symbol	Parameter		Conditions		Min	Тур	Max	Units		
Vo	Output Voltage		$T_{J} = 25^{\circ}C$		14.4	15	15.6	V		
V <sub>R LINE</sub>	Line Regulation		$T_J = 25^{\circ}C$	$17.5V \leq V_{I} \leq 30V$		130	300	mV		
				$20V \leq V_I \leq 30V$		110	250	1117		
V <sub>R LOAD</sub>	Load Regulation		$T_J = 25^{\circ}C$	$1.0 \text{ mA} \leq I_{O} \leq 100 \text{ mA}$		25	150	mV		
				$1.0 \text{ mA} \leq I_{O} \leq 40 \text{ mA}$		12	75	1117		
V <sub>O</sub>	Output Voltage (Note 2)		$17.5 V \leq V_{I} \leq 30 V$	$1.0 \text{ mA} \leq I_{O} \leq 40 \text{ mA}$	14.25		15.75	V		
			$17.5V \le V_I \le V_{Max}$	$1.0 \text{ mA} \leq I_{O} \leq 70 \text{ mA}$	14.25		15.75			
IQ	Quiescent Current		·			2.2	5.5	mA		
ΔlQ	Quiescent Current With Line Change With Load		$20V \leq V_I \leq 30V$				1.5	mA		
			$1.0 \text{ mA} \leq I_{O} \leq 40 \text{ mA}$				0.1	"		
No	Noise		T <sub>A</sub> = 25°C, 10 Hz ≤	$T_A = 25^{\circ}C$ , 10 Hz $\leq f \leq$ 100 kHz		90		μV		
$\Delta V_I/\Delta V_O$	Ripple Rejection		f = 120 Hz, 18.5V ≤	$f = 120 \text{ Hz}, 18.5 \text{V} \le \text{V}_{\text{I}} \le 28.5 \text{V}, \text{T}_{\text{J}} = 25 ^{\circ}\text{C}$		39		dB		
V <sub>DO</sub>	Dropout Voltage	Dropout Voltage				1.7		V		
I <sub>pk</sub> /I <sub>OS</sub>	Peak Output/Outpu Short Circuit Curren		T <sub>J</sub> = 25°C		$T_{J} = 25^{\circ}C$			140		mA
$\Delta V_{O}/\Delta T$	Average Temperatu Coefficient of Outpu		I <sub>O</sub> = 5.0 mA			-1.3		mV/°C		

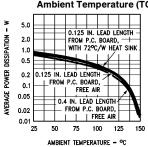
Note 1: The maximum steady state usable output current and input voltage are very dependent on the heat sinking and/or lead length of the package. The data above represent pulse test conditions with junction temperatures as indicated at the initiation of tests. Note 2: Power Dissipation  $\leq$  0.75W.

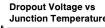
## **Equivalent Circuit**

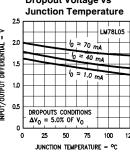


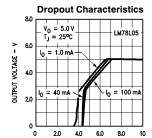
#### **Typical Performance Characteristics**

#### Worst Case Power Dissipation vs Ambient Temperature (TO-92)

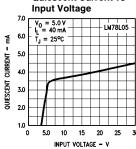




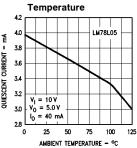




# **Quiescent Current vs**

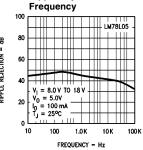


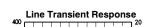
# **Quiescent Current vs**

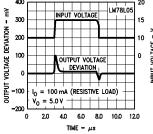


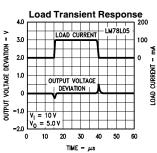
# Ripple Rejection vs

INPUT VOLTAGE - V









TL/H/10051-3

Note: Other LM78L00 Series devices have similar curves.

#### **Design Considerations**

The LM78L series regulators have thermal overload protection from excessive power, internal short-circuit protection which limits each circuit's maximum current, and output transistor safe-area protection for reducing the output current as the voltage across each pass transistor is increased.

Although the internal power dissipation is limited, the junction temperature must be kept below the maximum specified temperature (125°C) in order to meet data sheet specifications. To calculate the maximum junction temperature or heat sink required, the following thermal resistance values should be used:

Package	Typ	Max	Typ	Max
	θ <sub>J</sub> C	θ <sub>J</sub> C	θ <sub>JA</sub>	θ <sub>JA</sub>
TO-92			160	160

#### **Thermal Considerations**

The TO-92 molded package is capable of unusually high power dissipation due to the lead frame design. However, its thermal capabilities are generally overlooked because of a lack of understanding of the thermal paths from the semi-conductor junction to ambient temperature. While thermal resistance is normally specified for the device mounted 1 cm above an infinite heat sink, very little has been mentioned of the options available to improve on the conservatively rated thermal capability.

An explanation of the thermal paths of the TO-92 will allow the designer to determine the thermal stress he is applying in any given application.

#### The TO-92 Package

The TO-92 package thermal paths are complex. In addition to the path through the molding compound to ambient temperature, there is another path through the leads, in parallel with the case path, to ambient temperature, as shown in Figure 1.

The total thermal resistance in this model is then:

$$\theta_{\mathsf{JA}} = \frac{(\theta_{\mathsf{JC}} + \theta_{\mathsf{CA}}) (\theta_{\mathsf{JL}} + \theta_{\mathsf{LA}})}{\theta_{\mathsf{JC}} + \theta_{\mathsf{CA}} + \theta_{\mathsf{JL}} + \theta_{\mathsf{LA}}} \tag{1}$$

Where:

 $\theta_{
m JC}=$  thermal resistance of the case between the regulator die and a point on the case directly above the die location

 $\theta_{\mathrm{CA}} = \,$  thermal resistance between the case and air at ambient temperature.

θ<sub>JL</sub>= thermal resistance from regulator die through the input lead to a point ½ inch below the regulator case.

 $\theta_{LA}$  = total thermal resistance of the input/output ground leads to ambient temperature.

 $\theta_{JA}$  = junction to ambient thermal resistance.

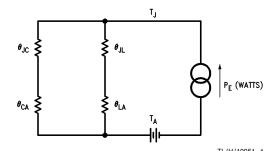


FIGURE 1. TO-92 Thermal Equivalent Circuit

#### **Methods of Heat Sinking**

With two external thermal resistances in each leg of a parallel network available to the circuit designer as variables, he can choose the method of heat sinking most applicable to his particular situation. To demonstrate, consider the effect of placing a small 72 °C/W flag type heat sink, such as the Staver F1-7D-2, on the LM78L00 molded case. The heat sink effectively replaces the  $\theta_{CA}$  (Figure 2) and the new thermal resistance,  $\theta^{\prime}_{JA}$ , equals 145 °C/W (assuming, 0.125 inch lead length).

The net change of 15 °C/W increases the allowable power dissipation to 0.86W with a minimal inserted cost. A still further decrease in  $\theta_{\rm JA}$  could be achieved by using a heat sink rated at 46 °C/W, such as the Staver FS-7A. Also, if the case sinking does not provide an adequate reduction in total  $\theta_{\rm JA}$ , the other external thermal resistance,  $\theta_{\rm LA}$ , may be reduced by shortening the lead length from package base to mounting medium. However, one point must be kept in mind. The lead thermal path includes a thermal resistance,  $\theta_{\rm SA}$ , from the leads at the mounting point to ambient, that is, the mounting medium.  $\theta_{\rm LA}$  is then equal to  $\theta_{\rm LS}+\theta_{\rm SA}$ . The new model is shown in Figure 2.

In the case of a socket,  $\theta_{SA}$  could be as high as 270 °C/W, thus causing a net increase in  $\theta_{JA}$  and a consequent decrease in the maximum dissipation capability. Shortening the lead length may return the net  $\theta_{JA}$  to the original value, but lead sinking would not be accomplished.

In those cases where the regulator is inserted into a copper clad printed circuit board, it is advantageous to have a maximum area of copper at the entry points of the leads. While it would be desirable to rigorously define the effect of PC board copper, the real world variables are too great to allow anything more than a few general observations.

#### Methods of Heat Sinking (Continued)

The best analogy for PC board copper is to compare it with parallel resistors. Beyond some point, additional resistors are not significantly effective; beyond some point, additional copper area is not effective.

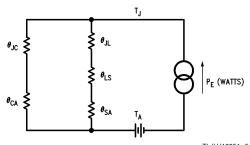
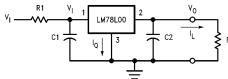
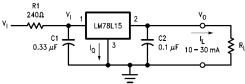


FIGURE 2. TO-92 Thermal Equivalent Circuit (Lead at other than Ambient Temperature)

### **High Dissipation Applications**



TL/H/10051-6



TL/H/10051-7

Where it is necessary to operate a LM78L00 regulator with a large input/output differential voltage, the addition of series resistor R1 will extend the output current range of the device by sharing the total power dissipation between R1 and the regulator.

$$R1 = \frac{V_{I \text{ Min}} - V_{O} - 2.0V}{I_{L \text{ Max}} + I_{Q}}$$
 (2)

IQ is the regulator quiescent current.

Regulator power dissipation at maximum input voltage and maximum load current is now

$$P_{D\;Max} = (V_1 - V_O)\,I_{L\;Max} + V_1\,I_Q \eqno(3)$$
 where:

$$V_1 = V_{IMax} - (I_{LMax} + I_Q) R1$$

The presence of R1 will affect load regulation according to the equation:

- load regulation (at constant V<sub>1</sub>)
- + line regulation (mV per V)
- $\times$  (RI)  $\times$  ( $\Delta$ I<sub>L</sub>).

As an example, consider a 15V regulator with a supply voltage of 30  $\pm 5.0$ V, required to supply a maximum load current of 30 mA. IQ is 4.3 mA, and minimum load current is to

$$R1 = \frac{25 - 15 - 2}{30 + 4.3} = \frac{8}{34.3} \approx 240\Omega \tag{5}$$

$$V_1 = 35 - (30 + 4.3) \ 0.24 = 35 - 8.2 = 26.8V$$

$$P_{D \text{ Max}} = (26.8 - 15) 30 + 26.8 (4.3)$$

= 354 + 115

= 470 mW, which permit operation up to 70°C in most applications.

Line regulation of this circuit is typically 110 mV for an input range of 25V-35V at a constant load current; i.e. 11 mV/V.

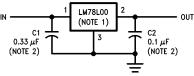
Load regulation = constant 
$$V_1$$
 load regulation (6)

(typically 10 mV, 10 mA-30 mA  $I_L$ ) + (11 mV/V) imes 0.24 imes 20 mA

(typically 53 mV)

= 63 mV for a load current change of 20 mA at a constant V<sub>I</sub> of 30V.

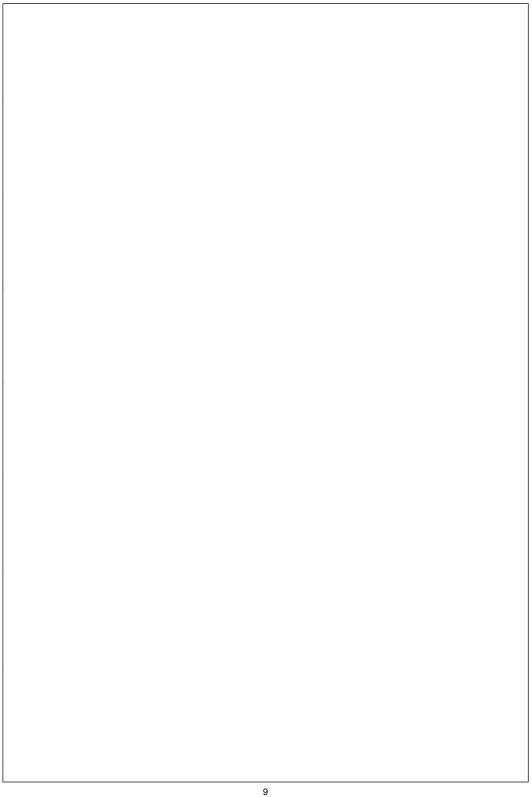
#### **Typical Applications**



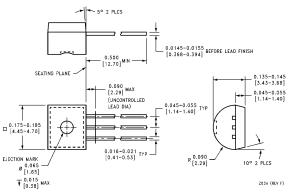
TL/H/10051-8

(4)

Note 1: To specify an output voltage, substitute voltage value for "00". Note 2: Bypass capacitors are recommended for optimum stability and transient response and should be located as close as possible to the regulator.



#### Physical Dimensions inches (millimeters)



Order Number LM78L05ACZ, LM78L09ACZ, LM78L12ACZ, LM78L15ACZ, LM78L62ACZ or LM78L82ACZ NS Package Number Z03A

#### LIFE SUPPORT POLICY

NATIONAL'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT OF NATIONAL SEMICONDUCTOR CORPORATION. As used herein:

- Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and whose failure to perform, when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
- A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.



National Semiconductor Corporation 1111 West Bardin Road Arlington, TX 76017 Tel: 1(800) 272-9959 Fax: 1(800) 737-7018 National Semiconductor Europe

Fax: (+49) 0-180-530 85 86 Email: cnjwge@tevm2.nsc.com Deutsch Tel: (+49) 0-180-530 85 85 English Tel: (+49) 0-180-532 78 32 Français Tel: (+49) 0-180-532 93 58 Italiano Tel: (+49) 0-180-534 16 80 National Semiconductor Hong Kong Ltd. 13th Floor, Straight Block, Ocean Centre, 5 Canton Rd. Tsimshatsui, Kowloon Hong Kong Tel: (852) 2737-1600 Fax: (852) 2736-9960 National Semiconductor Japan Ltd. Tel: 81-043-299-2309 Fax: 81-043-299-2408